EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	9	(tft or thin adj film adj transistor) and (source or drain) near4 (contact or electrode or pad or terminal) near6 (branching or interdigit\$4 or interleav\$4 or digit or fingers or comb) and (branch\$4 or interdigit\$4 or fingers or comb or digit or interleav\$4) near6 (spaced or separated or separation or gap or interval or apart or away or distanced) near4 (active or semiconductor or channel)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/03 10:20
L2	34	(tft or thin adj film adj transistor) and (source or drain) near4 (contact or electrode or pad or terminal) near6 (inkjet\$4 or ink or liquid or droplet or microdrop) same (contact or electrode or pad or terminal or source or drain) near8 (spaced or separated or separation or gap or interval or apart or away or distanced) near8 (active or semiconductor or channel)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	Ο̈́Ν	2007/10/03 10:18
L3	. 8	(tft or thin adj film adj transistor) and (source or drain) near4 (contact or electrode or pad or terminal) near6 (inkjet\$4 or ink or liquid or droplet or microdrop) same (inkjet\$4 or ink or liquid or drople or microdrop or drop-on) near8 (spaced or separated or separation or gap or interval or apart or away or distanced) near8 (active or semiconductor or channel)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/03 10:19
L4	8	(tft or thin adj film adj transistor) and (source or drain) near4 (contact or electrode or pad or terminal) near6 (branching or interdigit\$4 or interleav\$4 or digit or fingers or comb) and (digits or fingers or branches) near3 (narrow\$4 or widen\$4 or increasing or increased)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR .	ON	2007/10/03 10:21
S39	101	257/e29.039.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/01 10:39
S40	· 107	257/59.ccls. and (source or drain) near5 (finger or branch or branching or digit or digitat\$4 or interdigitat\$4 or comb) .	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/01 10:46
S41 •	50	257/57.ccls. and (source or drain) near5 (ink or inkjet or droplet or microdrop or nanodrop or liquid) .	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR .	ON .	2007/10/01 11:00
S42	342	257/59.ccls. and (source or drain) near5 (ink or inkjet or droplet or microdrop or nanodrop or liquid)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/01 11:02

10/3/07 10:25:52 AM

S43	137	257/e29.112.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/01 11:29
S44	449	438/674.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/01 12:14
S45	13	257/401.ccls. and (source or drain) near5 (ink or inkjet or droplet or microdrop or nanodrop or liquid)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/01 12:58
S46	123	257/347.ccls. and (source or drain) near5 (ink or inkjet or droplet or microdrop or nanodrop or liquid)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/01 12:59
S47	6	257/e21.174.ccls. and (source or drain) near5 (finger or branch or branching or digit or digitat\$4 or interdigitat\$4 or comb)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/01 13:20
S48	144	257/401.ccls. and (source or drain) near5 (finger or branch or branching or digit or digitat\$4 or interdigitat\$4 or comb)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/01 13:20
S49	291	257/e29.116.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/01 13:33
\$50	80	257/e21.174.ccls. and (source or drain) near5 (ink or inkjet or droplet or microdrop or nanodrop or liquid)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/01 13:45
S51	598	257/e29.117.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/01 13:58

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S52	14	(US-20060146219-\$ or US-20040214360-\$ or US-20050036094-\$ or US-20050071969-\$ or US-20050023557-\$ or US-20020008836-\$ or US-20020093474-\$ or US-20010043292-\$ or US-20030117362-\$ or US-20020145144-\$ or US-20030059984-\$).did. or (US-6157048-\$ or US-6750473-\$ or US-6159841-\$).did.	US-PGPUB; USPAT	OR	ON	2007/10/01 14:33
S53	1	"6545291".pn.	US-PGPUB; USPAT	OR	ON	2007/10/01 14:33
S54	1	438/666.ccls. and (source or drain) near5 (ink or inkjet or droplet or microdrop or nanodrop or liquid)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR .	ON	2007/10/01 15:17
S55	40	257/347.ccls. and (source or drain) near5 (finger or branch or branching or digit or digitat\$4 or interdigitat\$4 or comb)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/01 15:31
\$56	2	438/666.ccls. and (source or drain) near5 (finger or branch or branching or digit or digitat\$4 or interdigitat\$4 or comb)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/01 15:33
S57	400	(tft or thin adj film adj transistor) and (source or drain) near4 (contact or electrode or pad or terminal) near6 (branching or interdigit\$4 or fingers or comb)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/03 08:29
S58	203	(source near electrode) near5 (drain near electrode) near4 (interdigit\$4 or digit\$4 or comb)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/03 09:07
S59	188	(tft or thin adj film adj transistor) and (droplet or nanodrop or nanodroplet or ink or inkjet\$4) near4 (source or drain) near5 (electrode or contact or terminal or line or pad)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/03 09:26
\$60	61	(source or drain) near4 (electrode) near6 (branching or interdigit\$4 or digit\$4 or interleav\$4 or fingers or comb) and (source or drain or gate or semiconductor) near10 (droplet or inkjet\$4 or ink)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/03 09:45
S61	16	(tft or thin adj film adj transistor) and (semiconductor or active near region) near10 (droplet or inkjet\$4 or ink) and (semiconductor or active near region or channel) near3 (round or rounded or circular or circle)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/03 09:46

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S62	90	(tft or thin adj film adj transistor) and (semiconductor or active near region or alpha near si or amorphous near si or amorphous near silicon or alpha near silicon) near10 (droplet or inkjet\$4 or ink) and (semiconductor or active near region or channel or silicon) near10 (round or rounded or circular or circle)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/03 09:48
S63	35	(source near electrode) near5 (drain near electrode) near4 (interleav\$4)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/10/03 09:56
S64	14	(US-20060146219-\$ or US-20050036094-\$ or US-20050023557-\$ or US-20040214360-\$ or US-20030117362-\$ or US-20030059984-\$ or US-20020145144-\$ or US-20020093474-\$ or US-20020008836-\$ or US-20010043292-\$ or US-20050071969-\$).did. or (US-6750473-\$ or US-6159841-\$ or US-6157048-\$).did.	US-PGPUB; USPAT	OR	ON	2007/10/03 10:01

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Interference Search

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L5	29	((tft or thin adj film adj transistor) and (source or drain) near6 (branching or interdigit\$4 or interleav\$4 or digit or fingers or comb)).clm.	US-PGPUB	OR	ON	2007/10/03 10:33
L8	172	((tft or thin adj film adj transistor) and (source or drain) near2 (contact or electrode or pad or terminal) near6 (inkjet\$4 or ink or liquid or droplet or microdrop)).clm.	US-PGPUB	OR	ON	2007/10/03 10:28
L9	3	L5 and L8	US-PGPUB	OR	ON	2007/10/03 10:28
L10	0	((tft or thin adj film adj transistor) and (source or drain) near6 (branching or interdigit\$4 or interleav\$4 or digit or fingers or comb) and (branching or interdigit\$4 or interleav\$4 or digit or finger or comb) near3 (gap or interval or separat\$4 or spaced or spacing or distanced or distant) near2 (active or semiconductor or channel)).clm.	US-PGPUB	OR	ON	2007/10/03 10:30
L11	2	((tft or thin adj film adj transistor) and (active or channel) near2 (round or circular or circle)).clm.	US-PGPUB	OR	ON	2007/10/03 10:33
L12	0	((tft or thin adj film adj transistor) and (source or drain) near6 (branching or interdigit\$4 or interleav\$4 or digit or fingers or comb) and (branching or branch or digit or finger or comb) near2 (narrow\$4 or widen\$4 or increas\$4 or decreas\$4 or pointed or triangular)).clm.	US-PGPUB	OR	ON	2007/10/03 10:34